

Low-Voltage Single Asymmetrical SPDT Analog Switch

DESCRIPTION

The DG2020 is a single-pole/double-throw monolithic CMOS analog switch designed for high performance switching of analog signals. Combining low power, high speed, low on-resistance and small physical size, the DG2020 is ideal for portable and battery powered applications requiring high performance and efficient use of board space.

The DG2020 is built on Vishay Siliconix's low voltage J12 process. An epitaxial layer prevents latchup. Break-before-make is guaranteed.

The switch conducts equally well in both directions when on, and blocks up to the power supply level when off.

FEATURES

- Low voltage operation (2.7 V to 5.5 V)
- Low on-resistance - R_{ON}
 - NO = 0.8Ω
 - NC = 1.2Ω
- Low power consumption
- TTL/CMOS compatible
- TSOP-6 package

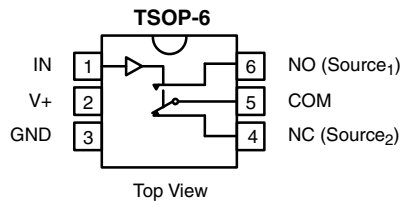
BENEFITS

- Reduced power consumption
- Simple logic interface
- High accuracy
- Reduce board space

APPLICATIONS

- Cellular phones
- Communication systems
- Portable test equipment
- Battery operated systems

FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION



Device Marking: E3xxx

TRUTH TABLE

LOGIC	NC	NO
0	ON	OFF
1	OFF	ON

ORDERING INFORMATION

TEMP. RANGE	PACKAGE	PART NUMBER
- 40 °C to 85 °C	TSOP-6	DG2020DV

ABSOLUTE MAXIMUM RATINGS

PARAMETERS	CONDITIONS	LIMITS	UNIT
V+	Reference to GND	- 0.3 to 6	V
IN, COM, NC, NO ^a	Reference to GND	- 0.3 to (V+ + 0.3 V)	
Continuous Current (any terminal)	Reference to GND	± 50	mA
Peak Current (pulsed at 1 ms, 10 % duty cycle)	Reference to GND	± 200	
Storage Temperature (D suffix)	Reference to GND	- 65 to + 125	°C
TSOP-6 ^c	Power Dissipation (packages) ^b	570	mW

Notes

- Signals on NC, NO, or COM or IN exceeding V+ will be clamped by internal diodes. Limit forward diode current to maximum current ratings.
- All leads welded or soldered to PC board.
- Derate 7 mW/C above 25 °C.



SPECIFICATION (V+ = 3 V)									
PARAMETER	SYMBOL	TEST CONDITION	TEMP. ^a	LIMITS (- 40 °C TO 85 °C)			UNIT		
		UNLESS OTHERWISE SPECIFIED, V+ = 3 V, ± 10 %, VIN = 0.4 V or 2 V ^e		MIN. ^b	TYP. ^c	MAX. ^b			
Analog Signal Range ^d	V _{NO} , V _{NC} , V _{COM}		Full	0	-	V+	V		
On-Resistance	R _{ON(NO)}	V+ = 2.7 V, V _{COM} = 1.5 V, I _{NO} , I _{NC} = 100 mA	Room	-	1.4	2	Ω		
	R _{ON(NC)}		Full	-	1.5	2.1			
			Room	-	2.2	3.2			
			Full	-	2.3	3.3			
R _{ON} Flatness ^d	R _{ON(NO)} Flatness	V+ = 2.7 V, V _{COM} = 0 V to V+, I _{NO} , I _{NC} = 100 mA	Room	-	0.42	-			
Switch Off Leakage Current ^f	I _{NO(off)} , I _{NC(off)}	V+ = 3.3 V, V _{NO} , V _{NC} = 1 V/3 V, V _{COM} = 3 V/1 V	Room	- 2.3	-	2.3	nA		
			Full	- 60	-	60			
	I _{COM (off)}		Room	- 2.3	-	2.3			
			Full	- 60	-	60			
Channel-On Leakage Current ^f	I _{COM(on)}	V+ = 3.3 V, V _{NO} , V _{NC} = V _{COM} = 1 V/3 V	Room	- 2.3	-	2.3			
			Full	- 60	-	60			
Digital Control									
Input High Voltage	V _{INH}		Full	2	-	-	V		
Input Low Voltage	V _{INL}		Full	-	-	0.4	V		
Input Capacitance	C _{IN}		Full	-	3.7	-	pF		
Input Current	I _{NL} or I _{NH}	V _{IN} = 0 or V+	Full	1	-	1	μA		
Dynamic Characteristics									
Turn-On Time	t _{ON(NO)}	V _{NO} or V _{NC} = 2 V, R _L = 300 Ω, C _L = 35 pF	Room	-	6	10	μs		
			Full	-	-	11			
	t _{ON(NC)}		Room	-	5	7			
			Full	-	-	8			
Turn-Off Time	t _{OFF(NO)}		Room	-	2	5			
			Full	-	-	5.5			
	t _{OFF(NC)}		Room	-	2	4			
			Full	-	-	4.5			
Break-Before-Make Time	t _d	V _{NO} or V _{NC} = 2 V, R _L = 300 Ω, C _L = 35 pF	Full	1	3	-			
Charge Injection ^d	Q _{INJ}	C _L = 1 nF, V _{GEN} = 0 V, R _{GEN} = 0 Ω	Room	-	1	-	pC		
Off-Isolation ^d	Q _{IRR}	R _L = 50 Ω, C _L = 5 pF, f = 1 MHz	Room	-	- 52	-	dB		
Crosstalk ^d	X _{TALK}		Room	-	- 53	-			
NO, NC Off Capacitance ^d	t _{ON(NO)}	V _{IN} = 0 or V+, f = 1 MHz	Room	-	75	-	pF		
	t _{ON(NC)}		Room	-	34	-			
Channel-On Capacitance ^d	t _{OFF(NO)}		Room	-	88	-			
	t _{OFF(NC)}		Room	-	95	-			
Power Supply									
Power Supply Range	V+			-	2.7	-		3.3	V
Power Supply Current	I+	V _{IN} = 0 or V+	Full	-	0.2	1	μA		
Power Consumption	P _C		Full	-	-	3.3	μW		

Notes

- a. Room = 25 °C, Full = as determined by the operating suffix.
- b. Typical values are for design aid only, not guaranteed nor subject to production testing.
- c. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this datasheet.
- d. Guarantee by design, nor subjected to production test.
- e. V_{IN} = input voltage to perform proper function.
- f. Guaranteed by 5 V leakage testing, not production tested.



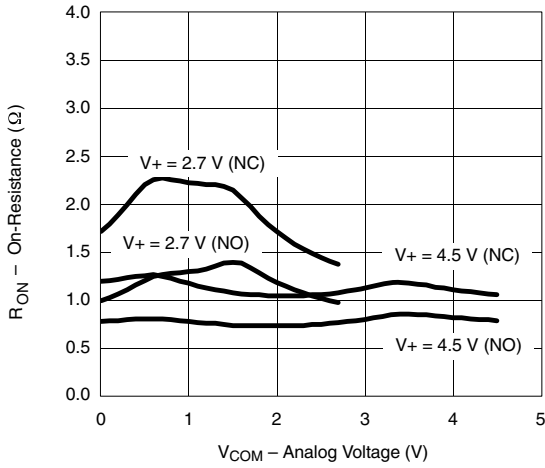
SPECIFICATION (V+ = 5 V)								
PARAMETER	SYMBOL	TEST CONDITION	TEMP. ^a	LIMITS (- 40 °C TO 85 °C)			UNIT	
		UNLESS OTHERWISE SPECIFIED, V+ = 5 V, ± 10 %, VIN = 0.8 V or 2.4 V ^e		MIN. ^b	TYP. ^c	MAX. ^b		
Analog Signal Range ^d	V _{NO} , V _{NC} , V _{COM}		Full	0	-	V+	V	
On-Resistance	R _{ON(NO)}	V+ = 4.5 V, V _{COM} = 3 V, I _{NO} , I _{NC} = 100 mA	Room	-	0.8	1.1	Ω	
	R _{ON(NC)}		Full	-	0.9	1.2		
			Room	-	1.2	1.6		
			Full	-	1.3	1.7		
R _{ON} Flatness ^d	R _{ON(NO)} Flatness	V+ = 4.5 V, V _{COM} = 0 V to V+, I _{NO} , I _{NC} = 100 mA	Room	-	0.13	-		
Switch Off Leakage Current	I _{NO(off)} , I _{NC(off)}	V+ = 5.5 V, V _{NO} , V _{NC} = 1 V/4.5 V, V _{COM} = 4.5 V/1 V	Room	- 5.3	-	5.3	nA	
	I _{COM (off)}		Full	- 98	-	98		
			Room	- 5.3	-	5.3		
			Full	- 98	-	98		
Channel-On Leakage Current	I _{COM(on)}	V+ = 5.5 V, V _{NO} , V _{NC} = V _{COM} = 1 V/4.5 V	Room	- 5.3	-	5.3		
			Full	- 98	-	98		
Digital Control								
Input High Voltage	V _{INH}		Full	2.4	-	-	V	
Input Low Voltage	V _{INL}		Full	-	-	0.8	V	
Input Capacitance	C _{IN}		Full	-	3.5	-	pF	
Input Current	I _{NL} or I _{NH}	V _{IN} = 0 or V+	Full	1	-	1	μA	
Dynamic Characteristics								
Turn-On Time	t _{ON(NO)}	V _{NO} or V _{NC} = 3 V, R _L = 300 Ω, C _L = 35 pF	Room	-	3	6	μs	
	t _{ON(NC)}		Full	-	-	6.5		
Turn-Off Time			t _{OFF(NO)}	Room	-	2		5
	Full			-	-	5.5		
	t _{OFF(NC)}		Room	-	1	4		
			Full	-	-	4.5		
			Room	-	1	3		
			Full	-	-	3.5		
Break-Before-Make Time	t _d	V _{NO} or V _{NC} = 3 V, R _L = 300 Ω, C _L = 35 pF	Full	0.3	1.5	-		
Charge Injection ^d	Q _{INJ}	C _L = 1 nF, V _{GEN} = 0 V, R _{GEN} = 0 Ω	Room	-	5	-	pC	
Off-Isolation ^d	Q _{IRR}	R _L = 50 Ω, C _L = 5 pF, f = 1 MHz	Room	-	- 53	-	dB	
Crosstalk ^d	X _{TALK}		Room	-	- 54	-		
NO, NC Off Capacitance ^d	t _{ON(NO)}	V _{IN} = 0 or V+, f = 1 MHz	Room	-	65	-	pF	
	t _{ON(NC)}		Room	-	32	-		
Channel-On Capacitance ^d	t _{OFF(NO)}		Room	-	90	-		
	t _{OFF(NC)}		Room	-	95	-		
Power Supply								
Power Supply Range	V+			4.5	-	5.5	V	
Power Supply Current	I+	V _{IN} = 0 or V+	Full	-	0.2	1	μA	
Power Consumption	P _C		Full	-	-	5.5	μW	

Notes

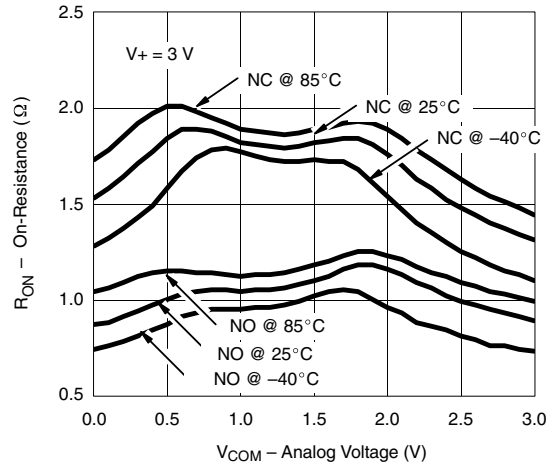
- a. Room = 25 °C, Full = as determined by the operating suffix.
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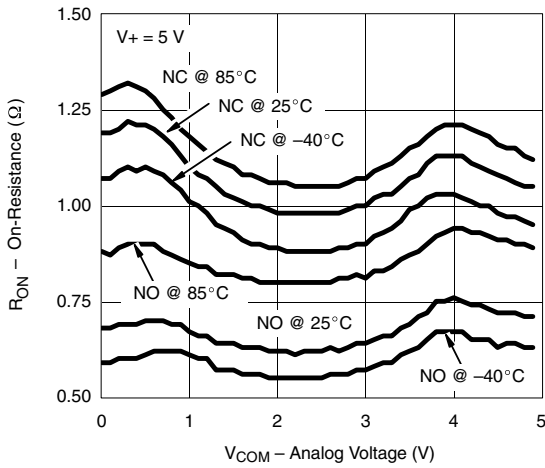
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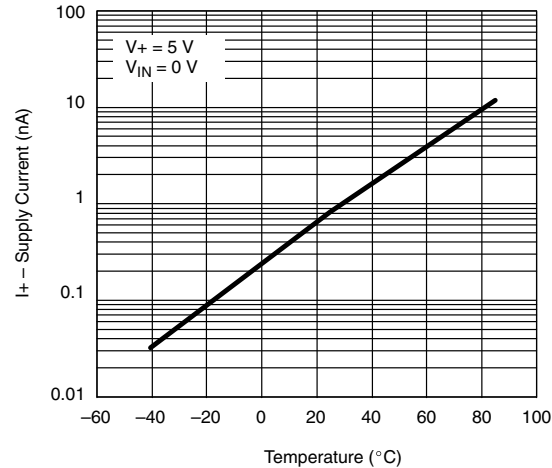
RON vs. VCOM and Supply Voltage



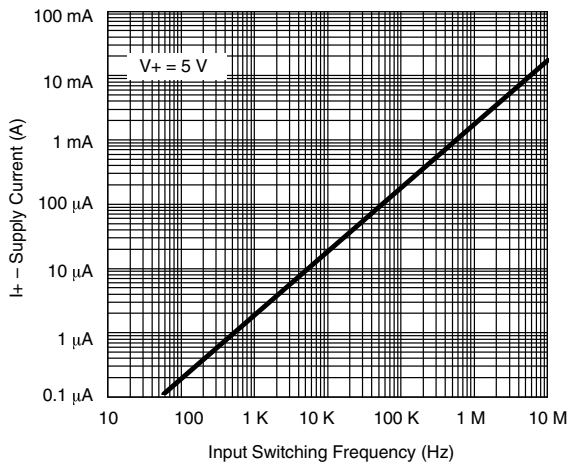
RON vs. Analog Voltage and Temperature



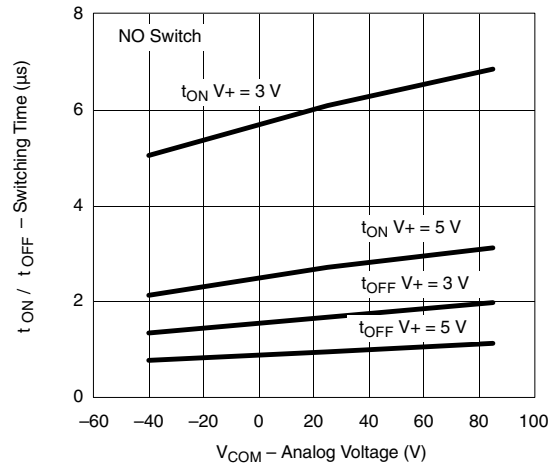
RON vs. Analog Voltage and Temperature



Supply Current vs. Temperature

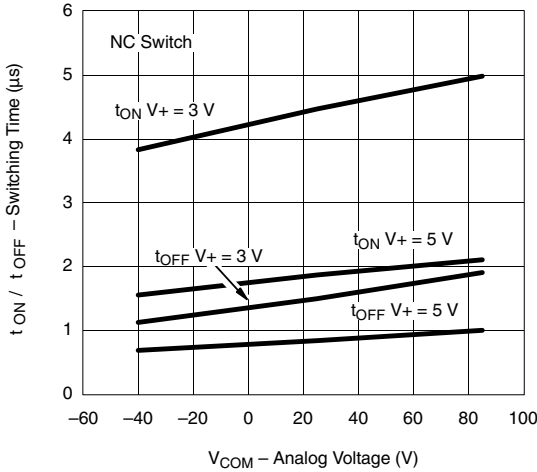


Supply Current vs. Input Switching Frequency

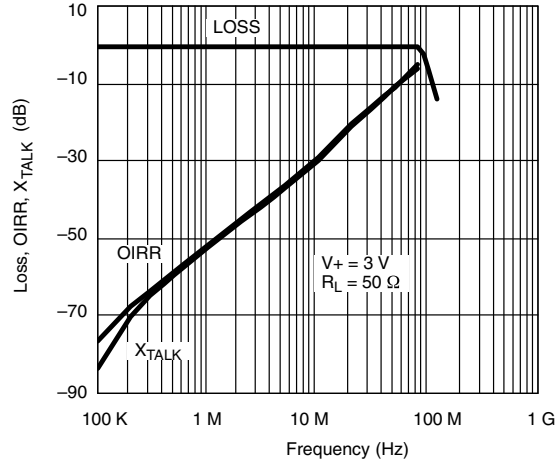


Switching Time vs. Temperature and Supply Voltage

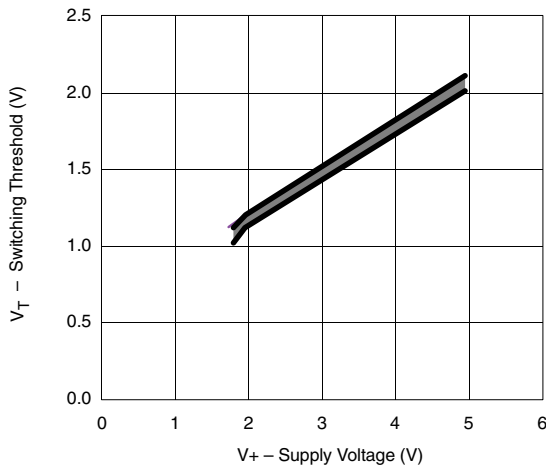
TYPICAL CHARACTERISTICS ($T_A = 25\text{ }^\circ\text{C}$, unless otherwise noted)



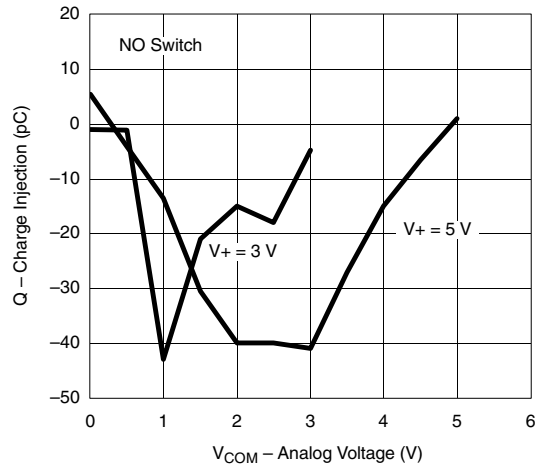
Switching Time vs. Temperature and Supply Voltage



Insertion Loss, Off-Isolation Crosstalk vs. Frequency

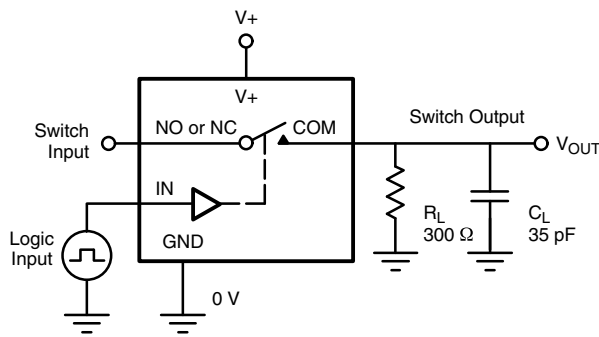


Switching Threshold vs. Supply Voltage



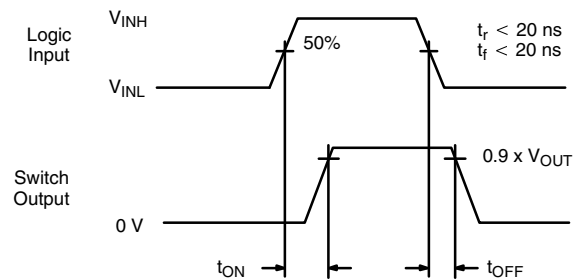
Charge Injection vs. Analog Voltage

TEST CIRCUITS



C_L (includes fixture and stray capacitance)

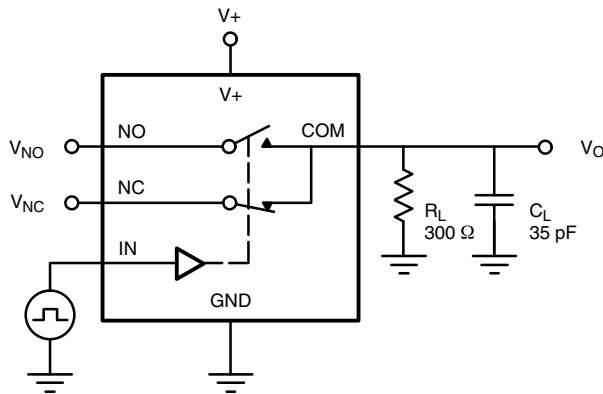
$$V_{OUT} = V_{COM} \left(\frac{R_L}{R_L + R_{ON}} \right)$$



Logic "1" = Switch On
Logic input waveforms inverted for switches that have the opposite logic sense.

Fig. 1 - Switching Time

TEST CIRCUITS



C_L (includes fixture and stray capacitance)

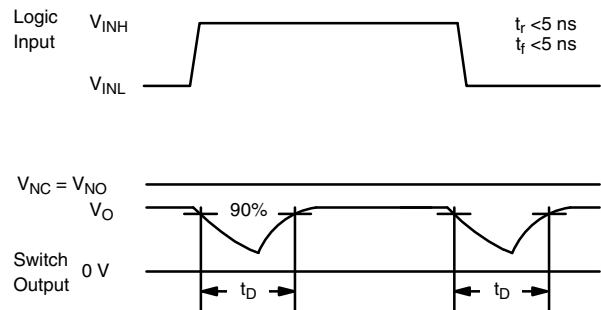
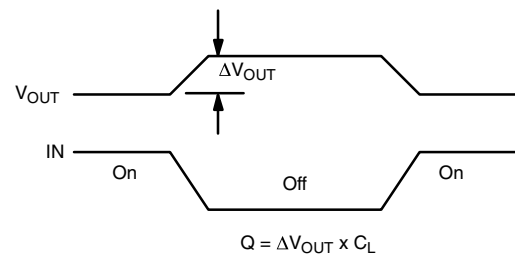
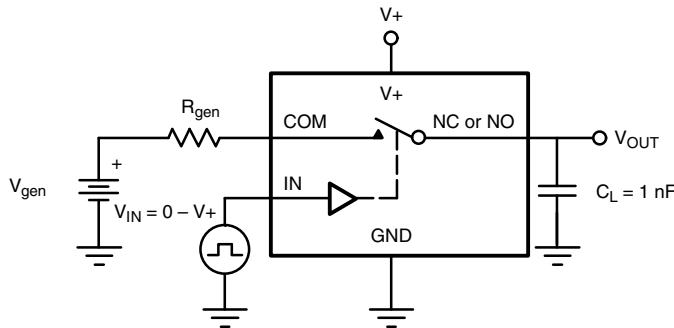


Fig. 2 - Break-Before-Make Interval



IN depends on switch configuration: input polarity determined by sense of switch.

Fig. 3 - Charge Injection

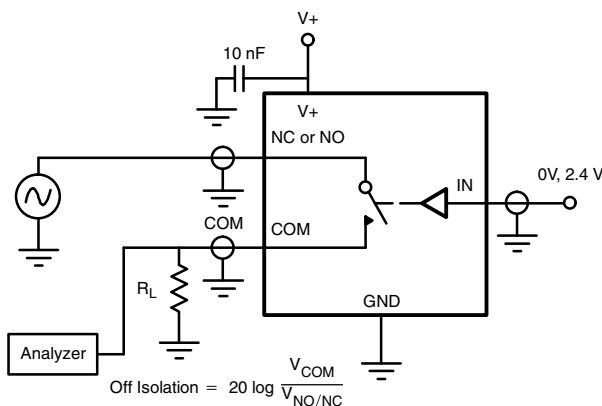


Fig. 4 - Off-Isolation

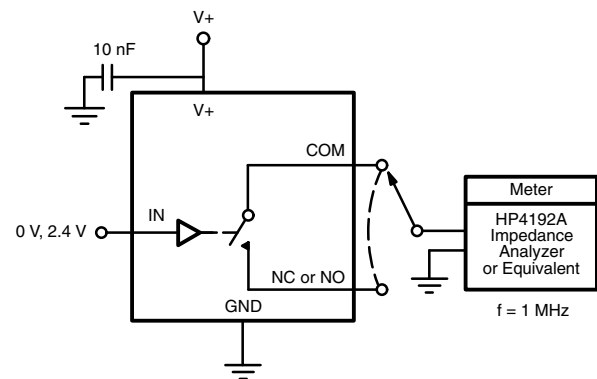


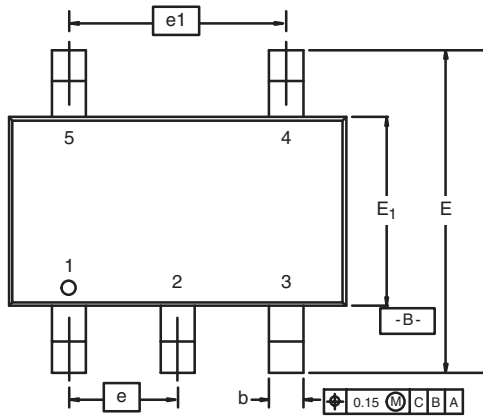
Fig. 5 - Channel off/on Capacitance

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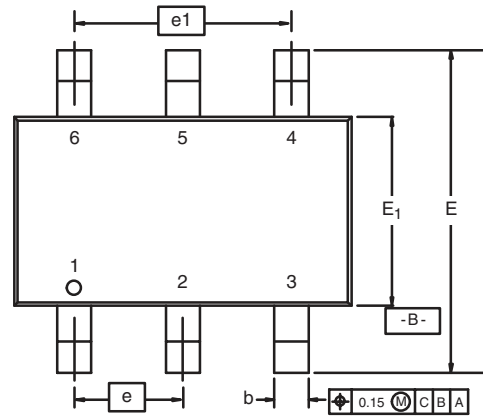


TSOP: 5/6-LEAD

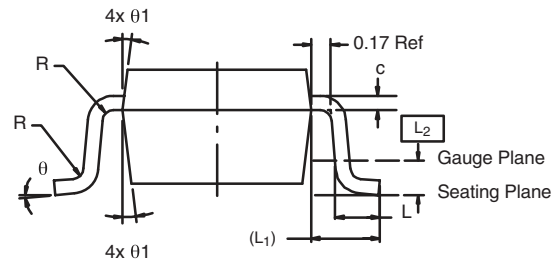
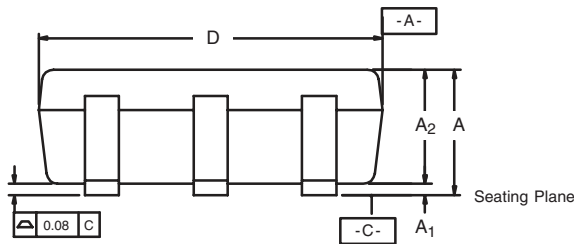
JEDEC Part Number: MO-193C



5-LEAD TSOP



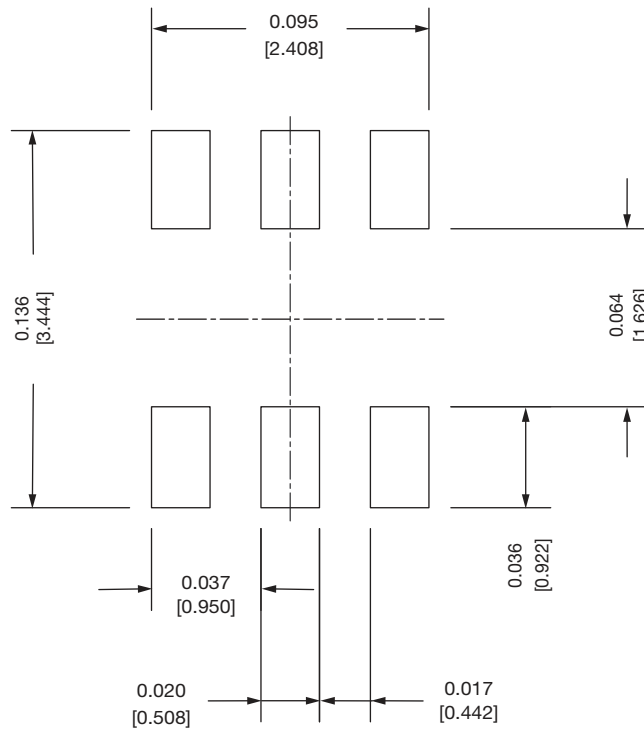
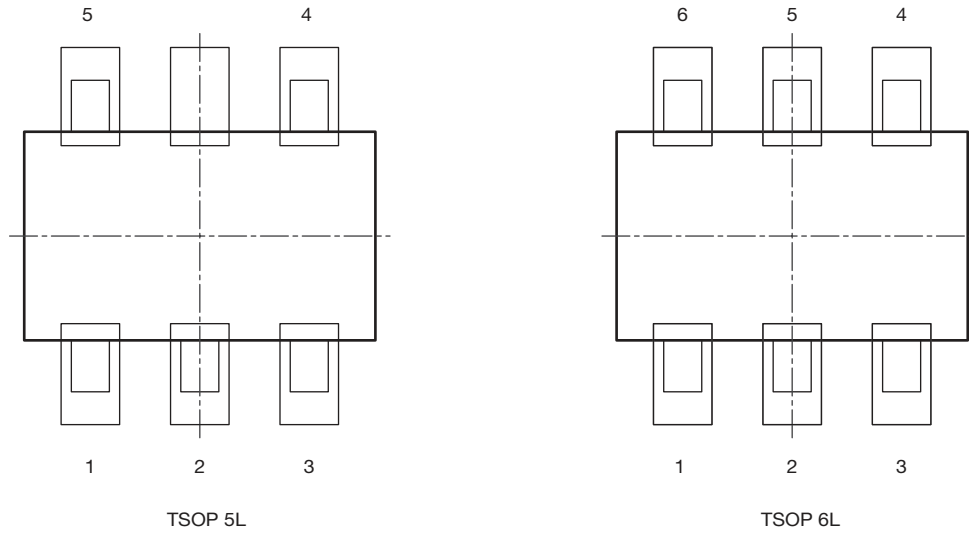
6-LEAD TSOP



Dim	MILLIMETERS			INCHES		
	Min	Nom	Max	Min	Nom	Max
A	0.91	-	1.10	0.036	-	0.043
A ₁	0.01	-	0.10	0.0004	-	0.004
A ₂	0.90	-	1.00	0.035	0.038	0.039
b	0.30	0.32	0.45	0.012	0.013	0.018
c	0.10	0.15	0.20	0.004	0.006	0.008
D	2.95	3.05	3.10	0.116	0.120	0.122
E	2.70	2.85	2.98	0.106	0.112	0.117
E ₁	1.55	1.65	1.70	0.061	0.065	0.067
e	0.95 BSC			0.0374 BSC		
e ₁	1.80	1.90	2.00	0.071	0.075	0.079
L	0.32	-	0.50	0.012	-	0.020
L ₁	0.60 Ref			0.024 Ref		
L ₂	0.25 BSC			0.010 BSC		
R	0.10	-	-	0.004	-	-
θ	0°	4°	8°	0°	4°	8°
θ ₁	7° Nom			7° Nom		
ECN: C-06593-Rev. I, 18-Dec-06						
DWG: 5540						



Recommended Land Pattern For TSOP-5L / TSOP-6L



Note

- All dimensions are in inches (millimeter)

ECN: C22-0860-Rev. B, 24-Oct-2022
 DWG: 3010



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